Environmental Stress Testing of Wafer-Level Au-Au Thermocompression Bonds Realized at Low Temperature: Strength and Hermeticity

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Hermeticity, reliability and strength of four laminates bonded at different temperatures by Au-Au thermocompression bonding have been investigated. Laminates with a diameter of 150 mm were realized by bonding a wafer containing membrane structures to a Si wafer with patterned bond frames. A bond tool pressure of 2266 mbar was applied for 15 minutes at temperatures ranging from 150–300 °C. The hermetic properties were estimated by membrane deflection measurements applying white-light interferometry after bonding. Reliability was tested by exposing the laminates to a steady-state life test, a thermal shock test, and a moisture resistance test. Bond strength was estimated by pull test measurements. A dicing yield above 90% was obtained for all laminates. Laminates bonded at 200 °C and above had significantly higher hermetic yield than the laminate bonded at 150 °C. No degradation in hermeticity was observed after the reliability tests. The maximum leakage rate (MLR) was estimated from two measurements of membrane deflection executed at two different times and was below 10−11 mbar·s−1. The average bond strength ranged from 44 to 175 MPa.

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Micro electro mechanical systems (MEMS) devices, especially inertial sensors, such as mechanical resonators, gyroscopes and accelerometers, can have fragile parts which need to be sealed in a high vacuum environment for high performance and long life time. A controlled ambient pressure is required in many of these devices because of their mechanical damping characteristics. MEMS absolute pressure sensors require a vacuum cavity as a zero pressure reference. Therefore, hermetic packaging is an essential requirement for such environment sensitive MEMS devices.

Metal thermocompression bonding is a promising technology for hermetic encapsulation of MEMS devices. Metals do not only provide hermetic seals for a longer duration than polymers and glasses but also enable significant reduction in die size because of smaller seal frames. Fraux and Baron reported that STMicroelectronics obtained die shrinkage of 57% by replacing the glass-frit bonding by Au-Au thermocompression bonding. Au is a promising metal for thermocompression bonding with a number of advantages: Au is a biocompatible material and can be used in harsh environments. There is no native oxide formed on the surface of Au, while on the surface of Cu and Al, a native oxide is formed. The absence of oxide enables direct contact between two opposing metals. The direct contact probably facilitates the formation of bonds between two metal bodies, and may allow bonding to be performed with lower pressure and/or at a lower temperature. Successful Au-Au thermocompression bonding has been reported in the temperature range 260 to 350 °C. A low bonding temperature bonding is generally desired in order to reduce the thermomechanically induced stress in the bonded devices. Bonding of sputter deposited Au films has been reported at temperatures as low as 100 °C. Bonding of porous Au has been performed at room temperature. To our knowledge, reports on the reliability and hermeticity of Au-Au thermocompression bonds have not yet been presented.

Hermeticity testing is commonly done in accordance with MIL-STD-883 test methods. However, the rejection leak rates mentioned in MIL-STD-883 are not valid for package volumes below 0.05 cm3. More stringent rejection rates for volumes below 0.01 cm3 are given in MIL-STD-750E. Traditionally, leak rates were determined by gross leak test. Bonding of sputter deposited Au films has been reported by Park et al. and by Xu et al. Reliability is a key factor of industrial MEMS devices. Various standardized test procedures that are relevant for different device specifications are available. MIL-STD-883 is one such standardized procedure, containing a list of exposure conditions and tests. In order to test the reliability of a bonded seal, a sub-set of exposure conditions is chosen. Even if the seal itself passes a specific exposure condition, it is possible that other properties of a functioning MEMS device is adversely affected by that specific exposure condition, so that the packaged device fails the reliability test even if the seal alone did pass the test.

This paper presents the effects of environmental stress on the bond strength and hermeticity of Au-Au thermocompression bonds. The initial screening of the die seals was done by optically measuring membrane deflection after bonding. To check the reliability of the bonded seals, changes in membrane deflection following steady-state life, thermal shock and moisture resistance tests were measured. A maximum leak rate (MLR) was also estimated by measuring the membrane deflection at two different times. The bond strength was investigated by counting the dicing yield of laminates and by pull test measurements on individual dies.

Experimental

Wafer design.— The top Si wafers (150 mm) had cavities with pressure-sensitive membranes. The cavities were sealed with bottom Si wafers consisting of bond frames of different widths. The cavity wafers had 481 membrane structures with nominal thickness 41 μm and nominal side edges of 2.5 mm × 2.5 mm. The membranes of sealed cavities deflected after bonding. The relationship between the membrane deflection and the pressure difference between the inside and outside of the sealed cavity is given by the following equation.

$$w = (a^b(1 - v^2)^3 \Delta P)/(66*d^{1.4} E)$$  [1]
The thickness of the top Si wafers was 400 μm. The membranes in the top wafers were made using tetra-methyl ammonium hydroxide (TMAH) etching. A thermal SiO₂ of 750 nm was used as masking material and the mask was not removed after the etching. The corresponding layer of SiO₂ on the front side of the wafer was patterned to write the die ID. The membranes were fully covered by SiO₂ on the front side. The bottom wafers were 400 μm thick with a 150 nm thick thermal SiO₂ layer. Before bonding, layers of 400 nm thick TiW and 1.2 μm thick Au were sputter deposited on all top and bottom wafers. The Au and TiW layers were patterned by wet etching on the top wafers and bottom wafers. The TiW was 50 μm wider than Au on the top wafer and 20 μm wider on the bottom wafer to avoid any direct contact between Au and Si and the subsequent formation of AuSi eutectic upon heating of the wafer stack.

**Bonding.**—The wafers were aligned and then bonded in an SB6e (Suss MicroTec) wafer bonder. The wafers were separated by spacers in the bonder after alignment. The ambient pressure in the bonding chamber was reduced to below 5 × 10⁻³ mbar before the spacers were removed. The thermocompression bonding was performed by applying a tool pressure of 2266 mbar (bond force of 5 kN) at bonding temperatures ranging from 150–300 °C for duration of 15 minutes. An overview of the bonding parameters of the four bonded laminates is given in Table II. The laminates ID have been constructed by numbers and letters having the following meaning: The prefix Au corresponds to the gold bonding and is followed by the bonding temperature (° C). The applied tool pressure corresponded to a bond pressure of 10 MPa. The pressure value is given just as a rough estimate, assuming a perfectly stiff material (rigid body) with parallel surfaces. It should be noted that the actual local pressure can have non-uniformities that are pattern dependent caused by the pressure loading properties of the bonding chuck, pressure diffuser and the silicon wafer.

The roughness and waviness of the surfaces will also cause the contact pressure to vary. It is still desirable to make comparisons between the different frame sizes (Table I), for which the difference in the contact pressure of different frames should be considered. We have chosen to roughly estimate the contact pressure of each bonding frame \( (\sigma_b) \) by the simple expression.

\[
\sigma_b = A_o F_{tool} / A_{bf} \approx 7.8 / A_{bf}
\]

Here, \( F_{tool} \) is the applied force of the bonding tool (5 kN), \( A_{bf} \) is the nominal bonding area of the particular frame (see Table I), \( A_d \) is the area of each die (5200 × 5200 μm), and \( A_o \) is the area of the Si wafer (0.01745 m²). This contact pressure is what one would have if each die was bonded separately as a rigid body with parallel...
surfaces under a pressure equal to the pressure on the wafer. This estimate ignores all horizontal components of stresses and maximizes the difference between the frame sizes. Using these simplifications, the calculated pressure on the 20 μm wide frames is 30 MPa and on the 200 μm wide frames is 3 MPa.

Reliability tests.— The laminates were stored for a minimum of 3 months after bonding and then diced along the diameter into two halves, each here called a half laminate. One half laminate of each laminate ID in Table I was subjected to environmental stress tests consisting of a steady-state life test, a thermal shock test, and a moisture resistance test. The other half was kept as a reference.

The first test was a steady-state life test in which the half laminates were exposed to 150 °C in an atmospheric environment for 1000 hours in an oven (Heraeus Instruments). Second, the same half laminates were exposed to a thermal shock test where a two chamber system connected with a lift was employed (Heraeus HT7012 S2). The top chamber was maintained at a constant temperature of +200 °C and the bottom chamber was maintained at −65 °C. A dwell time in each chamber of 10 min and a transition time of ∼7 s were employed. Consecutive exposure to both chambers was considered as 1 cycle and the samples were exposed for 50 cycles. Finally, the same half laminates were exposed to a moisture resistance test where a chamber with controlled humidity and temperature was used (Sunrise E series). A 24 h initial conditioning of the samples at 80 °C was done to completely dry out the samples. One complete cycle comprised of 7 steps and the humidity of the chamber was maintained at 90% for all the steps, as described in MIL-STD-883E. The temperature was varied between 25 °C to 65 °C during one cycle. The samples were exposed to 10 cycles. A subcycle of step 7 was performed for 5 of 10 cycles where humidity was uncontrolled and temperature was maintained at −10 °C (see MIL-STD-883E).

Characterization.— The amount of inward deflection of bonded membranes was measured by a Zygo NewView 6300 white light interferometer (WLI). The deflection measurements were done on all dies, and were repeated after a period of 3–5 months. The hermetic yield was defined as the percentage of membranes deflecting inwards by more than 2 μm after bonding. The open reference dies were left out of the hermetic yield calculation.

MLR was calculated by measuring the deflection of 1–13 membranes at two different times t1 and t2. Also the deflection of the membranes of the reference dies was measured in order to measure possible deviations from a flat surface. A maximum estimate for the leakage rate could therefore be calculated by the following equation.

\[
MLR = \frac{\Delta P^* V}{\Delta t}
\]

Here, V is the cavity volume (≈1.6 × 10^-6 l), and \(\Delta t\) is the time difference [s] between times \(t_1\) and \(t_2\). According to Eq. 1, a pressure increase of 72 mbar would result in a deflection decrease of 0.35 μm. In the calculation, the actual membrane dimensions, \(E = 165\ \text{GPa}\) and \(v = 0.28\) were used. Hence, if the measured deflection decreased by less than 0.35 μm, the increase in cavity pressure was lower than 72 mbar.

After environmental stressing, the membranes with inward deflection were identified by visual inspection and compared to a laminate map showing the membranes with inward deflection before environmental stressing. Four months after bonding, the laminates were diced into individual dies. Both the half laminates which had been stored and the half laminates which had been subjected to environmental stress were diced. The dicing yield, defined as the percentage of dies that were not delaminated after the dicing process, was recorded.

The dies which survived dicing test were used for subsequent pull tests, measuring the bond strength. 10 dies of F40R frame type was picked from each diced laminate including both their stressed and unstressed halves. The dies were glued to flat headed bolts and pull tested using a MiniMat2000 (Rheometric Inc.). The elongation versus applied force was recorded and the force, at which the fracture occurred, designated as the fracture force, was noted. The bond strength was calculated by dividing the fracture force by the actual bond area.

Results

Inward membrane deflection of the sealed cavities was observed after bonding. A picture of bonded laminate Au150 and Au200 is shown in Figure 3. The measured actual membrane thickness, inward deflection in membranes and calculated values of ΔP by Eq. 1 are listed in Table III. The measured deflection values indicate that the laminate Au200 had the lowest pressure and laminate Au300 had the highest pressure inside the sealed cavity. After a storage period of 3–5 months, an average change of −0.16 μm/m in membrane deflection of inward deflecting membranes was observed for all laminates with a standard deviation of 0.05 μm. An estimate for the MLR, calculated from Eq. 3 using a maximum deflection change of 0.35 μm/m (for details see Discussion section), is listed in Table III. The estimated MLR was below 10^-11 mbar · 1 · s^-1 for all laminates. There were no differences in the leak rate estimates for laminates bonded at different bonding temperature. There were also no differences in leak rates between the different frame widths. An average upward deflection of 0.4 μm was observed for the intentionally unsealed dies with a standard deviation of 0.2 μm.

The hermetic yield result of all bonded laminates is shown in Figure 4. Laminate Au250 had the highest hermetic yield with an average of 72% for all frame types. For the individual frame design F80R, a hermetic yield of 77.5% was obtained. Laminate Au300 showed an average low hermetic yield of 11%. Studies of pull tested dies showed that the reason of the low yield was misalignment of

![Figure 3. Pictures of bonded laminates Au150 (left) and Au200 (right). Hazy spots on the laminate are the inward deflecting membranes that indicate a good hermetic seal. (The wavy stripes are just a mirror image to emphasize the deflecting membranes.).](image)

Table III. Measured membrane deflections and cavity pressures as calculated from the inward membrane deflections. The maximum leak rate is calculated from corresponding values before environmental stressing.

<table>
<thead>
<tr>
<th>Laminate ID</th>
<th>Membrane Thickness [μm]</th>
<th>Measured Deflection [μm]</th>
<th>ΔP Calculated from Deflection [mbar]</th>
<th>Max. Leak Rate [mbar · 1 · s^-1]</th>
</tr>
</thead>
<tbody>
<tr>
<td>Au150</td>
<td>42</td>
<td>–</td>
<td>–</td>
<td>–</td>
</tr>
<tr>
<td>Au200</td>
<td>41.4</td>
<td>5.2</td>
<td>1118</td>
<td>1.4 × 10^-11</td>
</tr>
<tr>
<td>Au250</td>
<td>43</td>
<td>4.5</td>
<td>1087</td>
<td>1.4 × 10^-11</td>
</tr>
<tr>
<td>Au300</td>
<td>41</td>
<td>5.1</td>
<td>1057</td>
<td>1.4 × 10^-11</td>
</tr>
</tbody>
</table>
the wafers. The widest frame design (200 μm) on laminate Au300 had 56% yield, while frames of width 20 and 40 μm had 0% yield. Laminate Au150 had an average low hermetic yield of 7%, without any clear evidence of misalignment.

No membranes which were originally deflecting inwards after bonding had turned flat on any of the dies after exposure to 150 °C for 1000 h during steady-state life test. All laminates also survived the thermal shock test and moisture resistance test, showing no new flat membranes. Even laminate Au150 which had a low hermetic yield, had no changes in the number of deflecting dies caused by the environmental tests. There was no measurable effect of moisture or the exposure to sudden temperature variations on the hermeticity of the Au bonds.

The dicing yield results of stressed and un-stressed laminate halves are shown in Figures 5 and 6. The dicing yield of laminates Au150, Au200 and Au250 was above 97%, regardless of frame type. This shows that these laminates had bonds strong enough to survive the force exerted by the dicing saw during the dicing process. No significant effect of different frame width or geometry was observed on the dicing yield of these three laminates. For the half stressed laminate Au300, a dicing yield of 36% for frame F20R was observed. This dicing yield was significantly lower than the 88% dicing yield obtained for the wider frame widths.

Figure 7 shows the mean bond strength results of the pull tested dies from all stressed and unstressed half laminates. The mean bond strength of unstressed laminates ranged from 51–175 MPa, while mean bond strength of stressed laminates ranged from 44–156 MPa. When increasing the bonding temperature from 150 °C to 200 °C, the bond strength increased by more than 70 MPa for both unstressed and stressed laminates. When further increasing the bonding temperature from 250 °C to 300 °C, the bond strength decreased by more than 110 MPa for both unstressed and stressed laminates. No significant difference in bond strength between stressed and unstressed dies was observed for dies from any of the laminates.

The results of pull tested dies of all frame types from stressed half laminate Au200 are shown in Figure 8. Frame F20R had the lowest average fracture force of 37 N. Frames F20R and F200R had the lowest average bond strength of 10 MPa. Frames F20R, F40 and F40R had no significant difference in their bond strength; all had average bond strengths above 139 MPa.
As mentioned in the Results section, laminate Au300 was found to be misaligned. Hence, the reason of laminate Au300 showing low average hermetic yield and bond strength can be the misalignment of the laminate. Also a significant decrease in dicing yield of frame F20R was observed for laminate Au300 after environmental stressing. The low dicing yield of the stressed F20R frame may also have been due of its low tolerance to misalignment as it is narrower than the other frame types. Since the results obtained for the misaligned laminate Au300 are uncertain, they will not be further discussed in this section.

As seen in Figures 4 and 7, there was an increase of 46 percentage points in mean hermetic yield and an increase of 72 MPa in bond strength when increasing the bonding temperature from 150 to 200°C. While there was only an increase of 18 percentage points in mean hermetic yield and an increase of 24 MPa in bond strength when increasing the bonding temperature from 200 to 250°C. The increase in bond strength with increasing bonding temperature is caused by the increased diffusion of Au atoms with increasing temperature. The diffusion is controlled by an Arrhenius relationship with an exponential dependence on temperature. In our understanding, bonding between two Au surfaces occurs at initial contact points where the two Au surfaces are in direct contact. The number and area of these initial contact points are affected by the roughness of the two Au surfaces and by the applied bonding pressure. At the initial contact points, Au atoms can diffuse at the initial bonding interface, and grain growth and bonding can take place. The deformation of Au, creep and diffusion may also cause the contact points to increase in size, so that the bonded area expands. The maximum area that can be bonded is the area where the two Au surfaces overlap. Therefore, due to the diffusion dependency on temperature it is likely that the overlapping Au area that has been bonded is larger for higher temperatures. This could explain the increase in bond strength with increasing bonding temperature. The small difference in bond strength as the temperature was increased from 200°C to 250°C could indicate that the contact area between the bonding surfaces at 200 and 250°C was almost the same. The bonding temperatures used in our work for providing hermetic seals are lower than the previously reported temperatures of 320 and 400°C by Park et al.12 and Xu et al.13. Our results indicate that a lower limit of bonding temperature resulting in hermetic sealing is between 150 and 200°C for Au-Au thermocompression bonding for sputter deposited films applying a tool pressure of 2.3 bar. Also, the mean bond strengths obtained from our laminates was higher than the previously reported bond strength of ~20 MPa by Kurotaki et al.4 and ~10 MPa by Taklo et al.8

Table III shows that the calculated maximum leak rate of the bonded dies was below 10^{-11} mbar·s^{-1} for all laminates. The actual leak rate of the bonds may be significantly lower than the calculated 10^{-11} mbar·s^{-1} range; however the accuracy of the applied detection method prevented a better estimate. A leak in a die can be related to the pressure increasing within the sealed cavity over time. Considering uncertainties caused by the membrane thickness, the WLI scan position, and the atmospheric pressure, the maximum change in membrane deflection was over-estimated to 0.35 μm. The maximum deflection change of 0.35 μm was taken due to the following assumptions: a change in atmospheric pressure by 29 mbar would correspond to a change in membrane deflection by 0.14 μm, an error of 25 μm in measuring the same spot by WLI will correspond to a change in deflection by 0.05 μm and 0.16 μm was the measured change in deflection. In our work, the change in the deflection of the membranes was used only to monitor significant changes in pressure inside the sealed cavity. However, measured reductions in deflection could be related to possible (theoretical) leak rates. Our maximum estimated leak rates are factory 10 (Park et al.12) and 100 (Xu et al.13) lower than the previously published results. Leak rates between 10^{-11} and 10^{-10} mbar·s^{-1} are needed for various industrial applications.16 Our results indicate that Au-Au thermocompression bonds can meet requirements in this range.

The dicing yield above 90% of laminate Au150 suggests that even a bonding temperature of 150°C was sufficient to obtain a bond strong enough to survive the force exerted by the dicing saw. Even though laminate Au150 had low hermetic yield, the high dicing yield and mean bond strength above 59 MPa indicates that there were enough contact points between the opposing Au surfaces to make the bond strong, but not hermetic. There was no significant difference in dicing yield and bond strength between any of the laminates after environmental stressing (except the misaligned Au300). This suggests that the bonds were resistant to the environmental conditions encountered during the reliability tests. Deterioration of the bonds after environmental tests was observed by Malik et al. in case of Al-Al bonding.17 It seems that unlike Al, Au is a scaling material that does not deteriorate during the applied environmental tests, may be due to its noble nature.

As seen in Figure 8, the fracture force was similar for frames of width 40 μm and wider. This implies that the bond strength will decrease with increasing frame width, since bond strength is calculated by dividing fracture force by the area of the frame. When the fracture force is not dependent on the area, the bond strength parameter will still depend on the area. It seems likely that fracture force cannot increase with increase in frame width; therefore selecting a frame width of 40–80 μm over 200 μm seems a good choice for reducing the die area.

Conclusions

The strength, hermeticity and reliability of wafer-level Au-Au thermocompression bonds realized at temperatures 150–300°C were investigated in this paper. The results show that a bonding temperature higher than 150°C is required to produce laminates with a high hermetic yield when the applied bonding tool pressure is 2266 mbar and the bonding time is 15 minutes. Laminates bonded at or above 200°C had high hermetic yield and bond strength above 24 MPa. Unstressed laminates had a dicing yield above 97% and bond strength of 79 MPa, even at bonding temperature of 150°C. No deterioration of hermeticity was observed in any of the laminates following environmental stressing consisting of steady-state life test, thermal shock test and moisture resistance test. The fracture force was not dependent on the frame width. Frame F20R showed the lowest fracture force, while frames F40, F40R, F80R and F200R had fracture force between 65–75 N. The estimated maximum leak rate for all bonded laminates was below 10^{-11} mbar·s^{-1}.

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